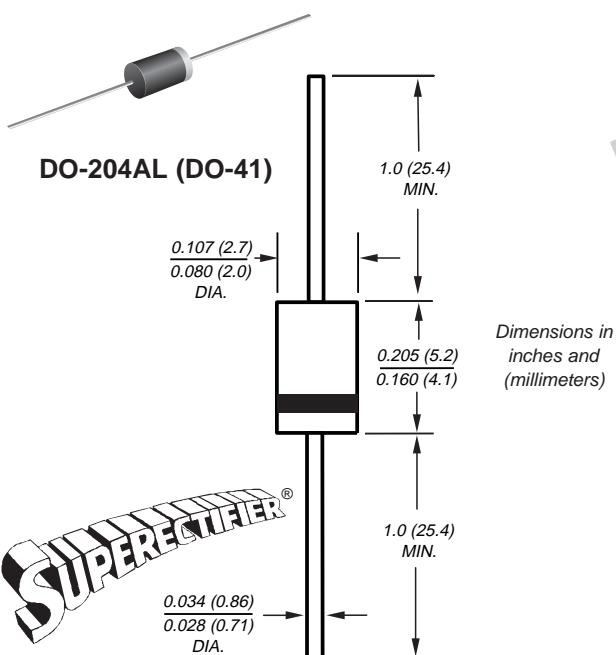


Glass Passivated Junction Rectifiers



NOTE: Lead diameter is $\frac{0.026 \text{ (0.66)}}{0.023 \text{ (0.58)}}$ for suffix "E" part numbers

*Glass-plastic encapsulation technique is covered by Patent No. 3,996,602, and brazed-lead assembly by Patent No. 3,930,306

Reverse Voltage
50 to 1600V
Forward Current 1.0A

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- 1.0 Ampere operation at $T_A = 75^\circ\text{C}$ and 55°C with no thermal runaway
- Typical I_{R} less than $0.1\mu\text{A}$
- High temperature soldering guaranteed: $350^\circ\text{C}/10$ seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-204AL, molded plastic over glass body

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.012 oz., 0.3 g

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	A	B	D	G	J	K	M	N	Q	T	V	W	Y	Unit
Maximum repetitive peak reverse voltage	V_{RRM}													V	
Maximum average forward rectified current 0.375" (9.5mm) lead length (See fig. 1)	$I_{\text{F(AV)}}$													A	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}					30					25			A	
Maximum full load reverse current, full cycle average, 0.375" (9.5mm) lead lengths at $T_A = 75^\circ\text{C}$	$I_{\text{R(AV)}}$							30						μA	
Typical thermal resistance (Note 1)	$R_{\theta JA}$							55						$^\circ\text{C/W}$	
Operating junction and storage temperature range	T_J, T_{STG}					-65 to +175				-65 to +150				$^\circ\text{C}$	

Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	A	B	D	G	J	K	M	N	Q	T	V	W	Y	Unit
Maximum instantaneous forward voltage at 1.0A	V_F			1.1				1.2			1.3			V	
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 125^\circ\text{C}$	I_{R}							5.0						μA	
Typical reverse recovery time at $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{\text{rr}} = 0.25\text{A}$	t_{rr}							3.0						μs	
Typical junction capacitance at 4.0V, 1MHz	C_J			8.0				7.0			5.0			pF	

Note: (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

GP10A thru GP10Y



Vishay Semiconductors
formerly General Semiconductor

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

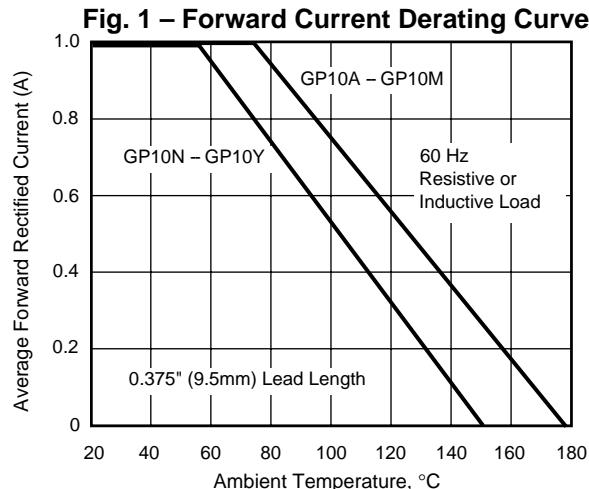


Fig 3. – Typical Instantaneous Forward Characteristics

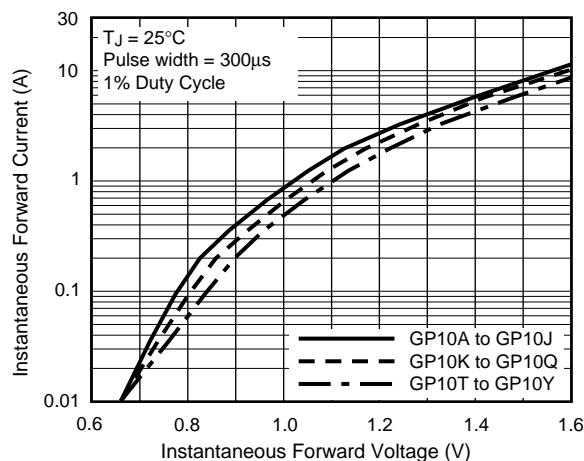


Fig 5. – Maximum Repetitive Peak Reverse Voltage, V_{RRM}

GP10A.....	50V
GP10B.....	100V
GP10D.....	200V
GP10G.....	400V
GP10J.....	600V
GP10K.....	800V
GP10M.....	1000V
GP10N.....	1100V
GP10Q.....	1200V
GP10T.....	1300V
GP10V.....	1400V
GP10W.....	1500V
GP10Y.....	1600V

Fig. 2 – Maximum Non-repetitive Peak Forward Surge Current

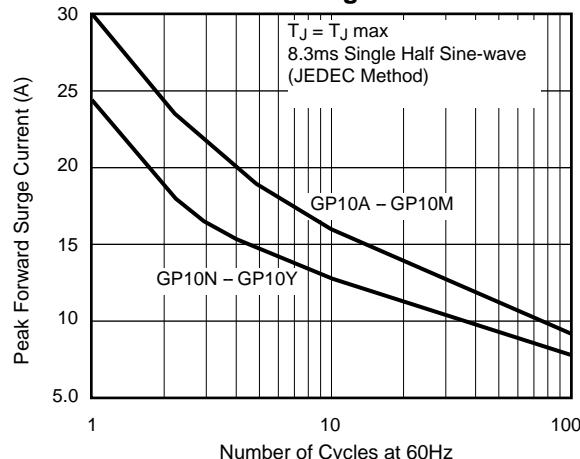


Fig 4. – Typical Reverse Characteristics

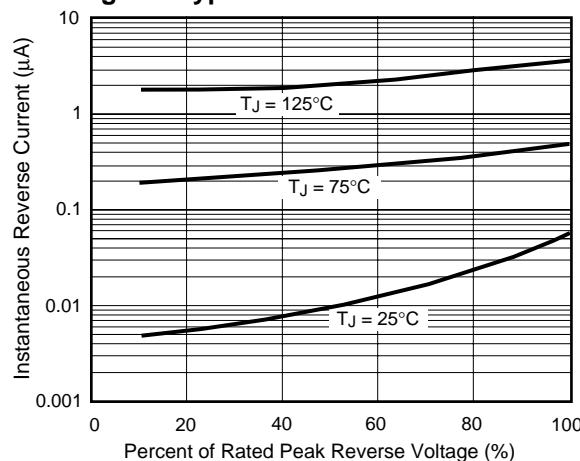


Fig 6. – Typical Junction Capacitance

